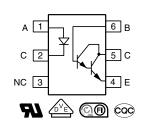
# H11B1, H11B2, H11B3

Vishay Semiconductors

# **Optocoupler, Photodarlington Output, High Gain,** with Base Connection





### DESCRIPTION

The H11B1, H11B2, H11B3 are industry standard optocouplers, consisting of a gallium arsenide infrared LED and a silicon photodarlington.

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### **FEATURES**

- Isolation test voltage: 5300 V<sub>RMS</sub>
- Coupling capacitance, 0.5 pF • Material categorization: For definitions of compliance please see

RoHS COMPLIANT

### **AGENCY APPROVALS**

www.vishay.com/doc?99912

- UL1577, file no. E52744 system code J
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- FIMKO EN60065, EN60950-1
- CQC: GB8898

ORDERING INFORMATION			
H 1 1 B PART NUMBER	# - X	00 (# PACKAGE OPTION	DIP 7.62 mm Option 7 Option 9 0,07 mm
AGENCY CERTIFIED/PACKAGE		CTR (%)	
UL, FIMKO, CQC	> 500	> 200	> 100
DIP-6	H11B1	H11B2	H11B3
SMD-6, option 7	H11B1-X007T <sup>(1)</sup>	-	-
SMD-6, option 9	H11B1-X009	H11B2-X009T <sup>(1)</sup>	-
UL, FIMKO, CQC, VDE	> 500	> 200	> 100
SMD-6, option 7	H11B1-X017	-	-

Notes

Additional options may be possible, please contact sales office. •

<sup>(1)</sup> Also available in tubes, no "T" in the end.

<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V <sub>R</sub>	3	V			
Forward continuous current		l <sub>F</sub>	60	mA			
Power dissipation		P <sub>diss</sub>	100	mW			
Derate linearly from 25 °C			1.33	mW/°C			
OUTPUT	·						
Collector emitter breakdown voltage		BV <sub>CEO</sub>	25	V			
Emitter collector breakdown voltage		BV <sub>ECO</sub>	7	V			
Collector base breakdown voltage		BV <sub>CBO</sub>	30	V			
Collector current (continuous)		Ι <sub>C</sub>	100	mA			
Power dissipation		P <sub>diss</sub>	150	mW			
Derate linearly from 25 °C			2	mW/°C			

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# H11B1, H11B2, H11B3

## **Vishay Semiconductors**

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
COUPLER							
Isolation test voltage between emitter and detector		V <sub>ISO</sub>	5300	V <sub>RMS</sub>			
Creepage distance			≥ 7	mm			
Clearance distance			≥ 7	mm			
Comparative tracking index per DIN IEC 112/VDE 0303, part 1		СТІ	175				
Isolation resistance	$V_{IO}$ = 500 V, $T_{amb}$ = 25 °C	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω			
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω			
Total package dissipation (LED plus detector)		P <sub>tot</sub>	260	mW			
Derate linearly from 25 °C			3.5	mW/°C			
Storage temperature		T <sub>stg</sub>	- 55 to + 150	°C			
Operating temperature		T <sub>amb</sub>	- 55 to + 100	°C			
Lead soldering time at 260 °C			10	S			

#### Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb}$ = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
	l <sub>F</sub> = 50 mA	H11B1	V <sub>F</sub>		1.1	1.5	V	
Forward voltage	$I_F = 30 IIIA$	H11B2	V <sub>F</sub>		1.1	1.5	V	
	I <sub>F</sub> = 10 mA	H11B3	V <sub>F</sub>		1.1	1.5	V	
Reverse current	V <sub>R</sub> = 3 V		I <sub>R</sub>			10	μA	
Junction capacitance	V <sub>F</sub> = 0 V, f = 1 MHz		Cj		50		pF	
OUTPUT								
Collector emitter breakdown voltage	$I_{\rm C}$ = 1 mA, $I_{\rm F}$ = 0 mA		BV <sub>CEO</sub>	30			V	
Emitter collector breakdown voltage	I <sub>E</sub> = 100μΑ, I <sub>F</sub> = 0 mA		BV <sub>ECO</sub>	7			V	
Collector base breakdown voltage	$I_C = 100 \ \mu A$ , $I_F = 0 \ m A$		BV <sub>CBO</sub>	30			V	
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, \text{ I}_{F} = 0 \text{ mA}$		I <sub>CEO</sub>			100	nA	
COUPLER								
Saturation voltage collector-emitter	I <sub>F</sub> = 1 mA, I <sub>C</sub> = 1 mA		V <sub>CEsat</sub>			1	V	
Capacitance (input to output)			CIO		0.5		pF	

#### Note

• Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
DC current transfer ratio	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 1 mA	H11B1	CTR <sub>DC</sub>	500			%
		H11B2	CTR <sub>DC</sub>	200			%
		H11B3	CTR <sub>DC</sub>	100			%

SWITCHING CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Switching times	$I_{F} = 5 \text{ mA}, V_{CF} = 10 \text{ V}, \text{ R}_{I} = 100 \Omega$	t <sub>on</sub>		5		μs	
Switching times	$r_F = 3 mA$ , $v_{CE} = 10 v$ , $n_L = 100 s_2$	t <sub>off</sub>		30		μs	

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### **TYPICAL CHARACTERISTICS** ( $T_{amb} = 25$ °C, unless otherwise specified)

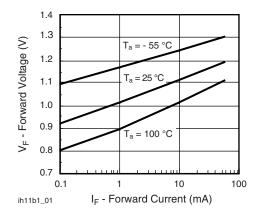


Fig. 1 - Forward Voltage vs. Forward Current

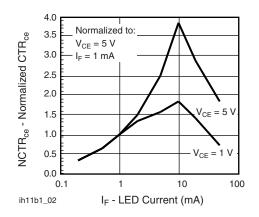
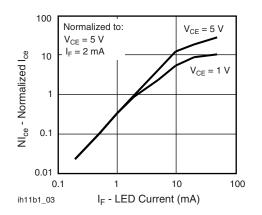


Fig. 2 - Normalized Non-Saturated and Saturated  $\text{CTR}_{\text{CE}}$  vs. LED Current





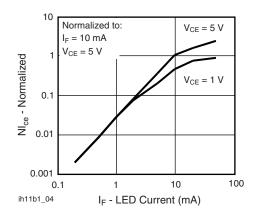


Fig. 4 - Normalized Non-Saturated and Saturated Collector Emitter Current vs. LED Current

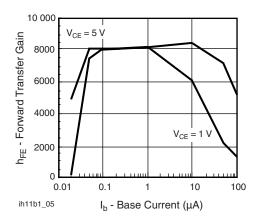


Fig. 5 - Non-Saturated and Saturated  $h_{\text{FE}} \, \text{vs.}$  Base Current

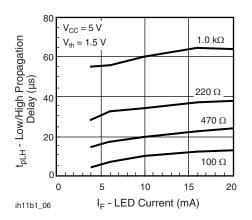


Fig. 6 - Low to High Propagation Delay vs. Collector Load Resistance and LED Current

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# H11B1, H11B2, H11B3

## Vishay Semiconductors

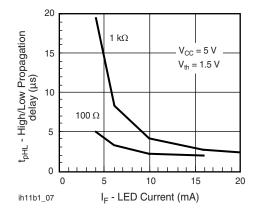
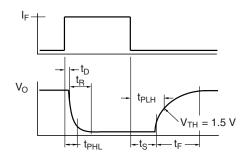


Fig. 7 - High to Low Propagation Delay vs. Collector Load Resistance and LED Current



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Fig. 8 - Switching Waveform

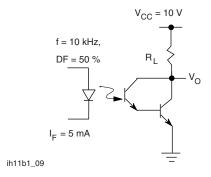


Fig. 9 - Switching Schematic

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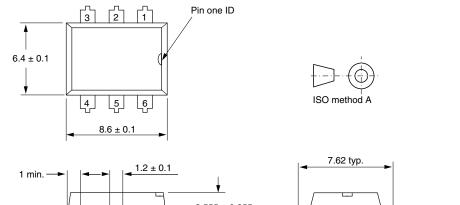
# H11B1, H11B2, H11B3

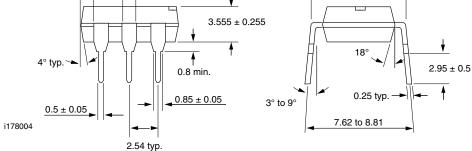
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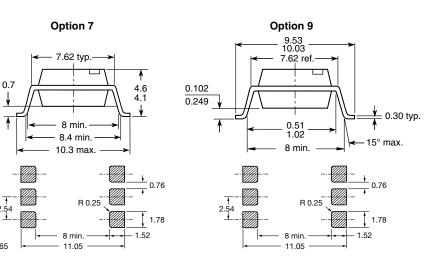
### **PACKAGE DIMENSIONS** in millimeters

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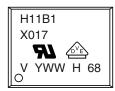
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### **PACKAGE MARKING**



#### Notes

- Only options 1, 7, and 9 are reflected in the package marking. •
- The VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking. •

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